

SN54AHC00, SN74AHC00 QUADRUPLE 2-INPUT POSITIVE-NAND GATES

SCLS227A – OCTOBER 1995 – REVISED MARCH 1996

- Operating Range: 2-V to 5.5-V V_{CC}
- **EPIC™** (Enhanced-Performance Implanted CMOS) Process
- High Latch-Up Immunity Exceeds 250 mA Per JEDEC Standard JESD-17
- ESD Protection Exceeds 2000 V Per MIL-STD-883C, Method 3015; Exceeds 200 V Using Machine Model (C = 200 pF, R = 0)
- Package Options Include Plastic Small-Outline (D), Shrink Small-Outline (DB), Thin Shrink Small-Outline (PW), and Ceramic Flat (W) Packages, Ceramic Chip Carriers (FK), and Standard Plastic (N) and Ceramic (J) 300-mil DIPs

description

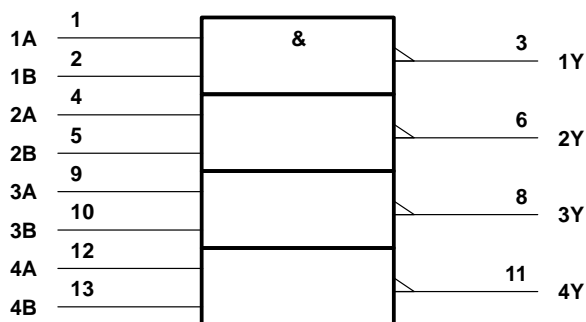
The 'AHC00 perform the Boolean function $Y = \overline{A \bullet B}$ or $Y = \overline{A} + \overline{B}$ in positive logic.

The SN54AHC00 is characterized for operation over the full military temperature range of -55°C to 125°C . The SN74AHC00 is characterized for operation from -40°C to 85°C .

FUNCTION TABLE
(each gate)

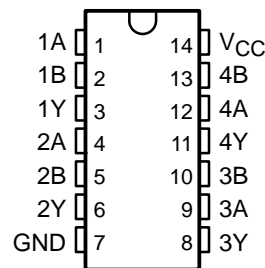
INPUTS		OUTPUT
A	B	Y
H	H	L
L	X	H
X	L	H

logic symbol†

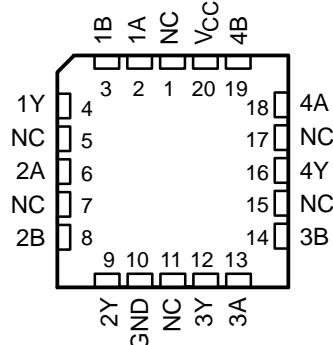


† This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12. Pin numbers shown are for the D, DB, J, N, PW, and W packages.

SN54AHC00 . . . J OR W PACKAGE
SN74AHC00 . . . D, DB, N, OR PW PACKAGE
(TOP VIEW)



SN54AHC00 . . . FK PACKAGE
(TOP VIEW)



NC – No internal connection



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SN54AHC00, SN74AHC00

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logic diagram, (positive logic)



absolute maximum ratings over operating free-air temperature range (unless otherwise noted)[†]

Supply voltage range, V_{CC}	–0.5 V to 7 V
Input voltage range, V_I (see Note 1)	–0.5 V to 7 V
Output voltage range, V_O (see Note 1)	–0.5 V to $V_{CC} + 0.5$ V
Input clamp current, I_{IK} ($V_I < 0$)	–20 mA
Output clamp current, I_{OK} ($V_O < 0$ or $V_O > V_{CC}$)	±20 mA
Continuous output current, I_O ($V_O = 0$ to V_{CC})	±25 mA
Continuous current through V_{CC} or GND	±50 mA
Maximum power dissipation at $T_A = 55^\circ\text{C}$ (in still air) (see Note 2): D package	1.25 W
DB or PW package	0.5 W
N package	1.1 W
Storage temperature range, T_{stg}	–65°C to 150°C

[†] Stresses beyond those listed under “absolute maximum ratings” may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under “recommended operating conditions” is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

- NOTES: 1. The input and output voltage ratings may be exceeded if the input and output current ratings are observed.
2. The maximum package power dissipation is calculated using a junction temperature of 150°C and a board trace length of 750 mils, except for the N package, which has a trace length of zero.

recommended operating conditions (see Note 3)

			SN54AHC00		SN74AHC00		UNIT
			MIN	MAX	MIN	MAX	
V _{CC}	Supply voltage		2	5.5	2	5.5	V
V _{IH}	High-level input voltage	V _{CC} = 2 V	1.5		1.5		V
		V _{CC} = 3 V	2.1		2.1		
		V _{CC} = 5.5 V	3.85		3.85		
V _{IL}	Low-level input voltage	V _{CC} = 2 V	0.5		0.5		V
		V _{CC} = 3 V	0.9		0.9		
		V _{CC} = 5.5 V	1.65		1.65		
V _I	Input voltage		0	5.5	0	5.5	V
V _O	Output voltage		0	V _{CC}	0	V _{CC}	V
I _{OH}	High-level output current	V _{CC} = 2 V	−50		−50		μA
		V _{CC} = 3.3 V ± 0.3 V	−4		−4		mA
		V _{CC} = 5 V ± 0.5 V	−8		−8		
I _{OL}	Low-level output current	V _{CC} = 2 V	50		50		μA
		V _{CC} = 3.3 V ± 0.3 V	4		4		mA
		V _{CC} = 5 V ± 0.5 V	8		8		
Δt/Δv	Input transition rise or fall rate	V _{CC} = 3.3 V ± 0.3 V	100		100		ns/V
		V _{CC} = 5 V ± 0.5 V	20		20		
T _A	Operating free-air temperature		−55	125	−40	85	°C

NOTE 3: Unused inputs must be held high or low to prevent them from floating.

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electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS	V _{CC}	T _A = 25°C			SN54AHC00		SN74AHC00		UNIT
			MIN	TYP	MAX	MIN	MAX	MIN	MAX	
V _{OH}	I _{OH} = -50 µA	2 V	1.9	2		1.9		1.9		V
		3 V	2.9	3		2.9		2.9		
		4.5 V	4.4	4.5		4.4		4.4		
	I _{OH} = -4 mA	3 V	2.58			2.48		2.48		
	I _{OH} = -8 mA	4.5 V	3.94			3.8		3.8		
V _{OL}	I _{OL} = 50 µA	2 V			0.1		0.1		0.1	V
		3 V			0.1		0.1		0.1	
		4.5 V			0.1		0.1		0.1	
	I _{OL} = 4 mA	3 V			0.36		0.5		0.44	
	I _{OL} = 8 mA	4.5 V			0.36		0.5		0.44	
I _I	A or B inputs	V _I = V _{CC} or GND	5.5 V		±0.1		±1		±1	µA
I _{CC}	V _I = V _{CC} or GND, I _O = 0	5.5 V			2		20		20	µA
C _i	V _I = V _{CC} or GND	5 V		2	10				10	pF

switching characteristics over recommended operating free-air temperature range,
V_{CC} = 3.3 V ± 0.3 V (unless otherwise noted) (see Figure 1)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	OUTPUT CAPACITANCE	SN54AHC00				UNIT	
				T _A = 25°C			MIN		MAX
				MIN	TYP	MAX			
t _{PLH} *	A or B	Y	C _L = 15 pF	5.5	7.9	1	9.5	ns	
t _{PHL} *				5.5	7.9	1	9.5		
t _{PLH}	A or B	Y	C _L = 50 pF	8	11.4	1	13	ns	
t _{PHL}				8	11.4	1	13		

* On products compliant to MIL-PRF-38535, this parameter is ensured but not production tested.

switching characteristics over recommended operating free-air temperature range,
V_{CC} = 3.3 V ± 0.3 V (unless otherwise noted) (see Figure 1)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	OUTPUT CAPACITANCE	SN74AHC00				UNIT	
				T _A = 25°C			MIN		MAX
				MIN	TYP	MAX			
t _{PLH}	A or B	Y	C _L = 15 pF	5.5	7.9	1	9.5	ns	
t _{PHL}				5.5	7.9	1	9.5		
t _{PLH}	A or B	Y	C _L = 50 pF	8	11.4	1	13	ns	
t _{PHL}				8	11.4	1	13		



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**switching characteristics over recommended operating free-air temperature range,
V_{CC} = 5 V ± 0.5 V (unless otherwise noted) (see Figure 1)**

PARAMETER	FROM (INPUT)	TO (OUTPUT)	OUTPUT CAPACITANCE	SN54AHC00				UNIT
				T _A = 25°C			MIN	MAX
				MIN	TYP	MAX		
t _{PLH} *	A or B	Y	C _L = 15 pF	3.7	5.5	1	6.5	ns
t _{PHL} *				3.7	5.5	1	6.5	
t _{PLH}	A or B	Y	C _L = 50 pF	5.2	7.5	1	8.5	ns
t _{PHL}				5.2	7.5	1	8.5	

* On products compliant to MIL-PRF-38535, this parameter is ensured but not production tested.

**switching characteristics over recommended operating free-air temperature range,
V_{CC} = 5 V ± 0.5 V (unless otherwise noted) (see Figure 1)**

PARAMETER	FROM (INPUT)	TO (OUTPUT)	OUTPUT CAPACITANCE	SN74AHC00				UNIT
				T _A = 25°C			MIN	MAX
				MIN	TYP	MAX		
t _{PLH}	A or B	Y	C _L = 15 pF	3.7	5.5	1	6.5	ns
t _{PHL}				3.7	5.5	1	6.5	
t _{PLH}	A or B	Y	C _L = 50 pF	5.2	7.5	1	8.5	ns
t _{PHL}				5.2	7.5	1	8.5	

noise characteristics, V_{CC} = 5 V, C_L = 50 pF, T_A = 25°C (see Note 4)

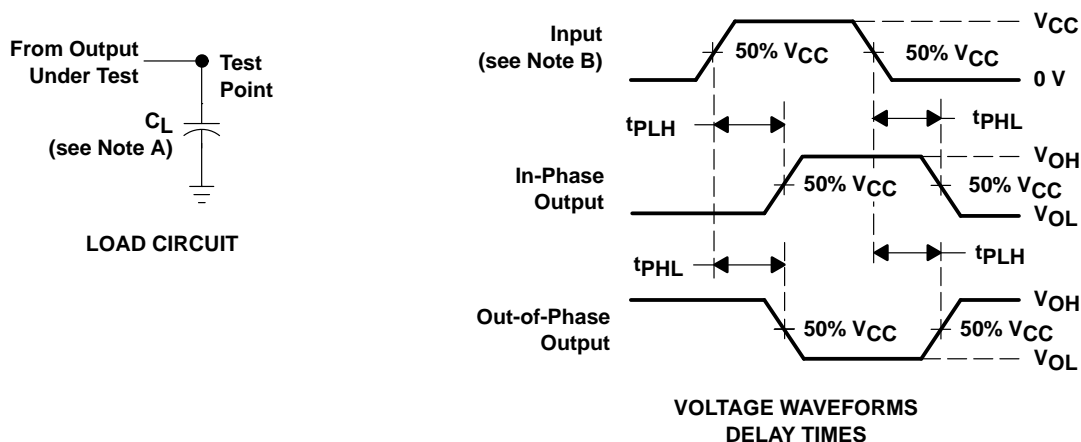
PARAMETER		SN74AHC00			UNIT
		MIN	TYP	MAX	
V _{OL(P)}	Quiet output, maximum dynamic V _{OL}	0.3	0.8		V
V _{OL(V)}	Quiet output, minimum dynamic V _{OL}	−0.3	−0.8		V
V _{OH(V)}	Quiet output, minimum dynamic V _{OH}	4.6			V
V _{IH(D)}	High-level dynamic input voltage	3.5			V
V _{IL(D)}	Low-level dynamic input voltage		1.5		V

NOTE 4: Characteristics are determined during product characterization and ensured by design for surface-mount packages only.

operating characteristics, V_{CC} = 5 V, T_A = 25°C

PARAMETER		TEST CONDITIONS	TYP	UNIT
C _{pd}	Power dissipation capacitance	No load, f = 1 MHz	9.5	pF

PARAMETER MEASUREMENT INFORMATION



- NOTES: A. C_L includes probe and jig capacitance.
B. All input pulses are supplied by generators having the following characteristics: $PRR \leq 1\text{ MHz}$, $Z_O = 50\ \Omega$, $t_r = 3\text{ ns}$, $t_f = 3\text{ ns}$.
C. The outputs are measured one at a time with one input transition per measurement.

Figure 1. Load Circuit and Voltage Waveforms

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